

IGD-8-426-E1F12-BH-FA



IGBT Module Stack

Three-phase inverter

SEMIKUBE - Size 3H

IGD-8-426-E1F12-BH-FA

Preliminary Data

Features

- Highly compact
- Integrated current, voltage and temperature sensors
- Easy maintenance
- Easy mounting and dismounting
- Very high Life-Time Expectancy
- Very low inductive DC bus

Typical Applications

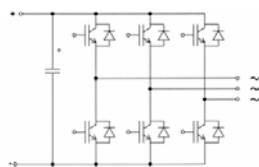
- Industrial
- AC motor control
- UPS
- Solar inverter
- Oil and gas pumps

No. 08800900

Footnotes

Electrical parameters to be derated for $T_{amb} > 40^{\circ}\text{C}$

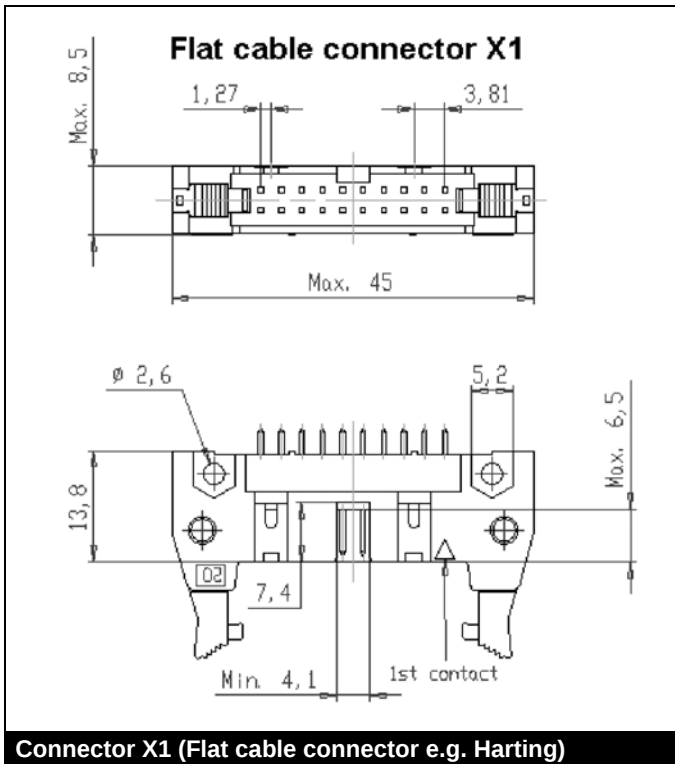
Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
Electrical Data					
I_{rms}	$T_{amb}=40^{\circ}\text{C}$, 3kHz, 650V _{dc} , 400V _{ac} , cos=0,85	no overload		1490	A
		110% overload, 60s every 10min		1460	A
		150% overload, 60s every 10min		1140	A
V_{CES}				1200	V
f_{sw}	max. switching frequency			15.6	kHz
V_{DC}	DC voltage applied to the capacitor bank			750	V
V_{AC}	network voltage (line side), -20% / +15%			460	V
V_{isol}	50Hz / 1min			2500	V
P_{tot}	$T_{amb}=40^{\circ}\text{C}$			11720	W
T_j	T_{vj} for continous operation	-40		125	$^{\circ}\text{C}$
Capacitor Data					
C_{DC}	SKC4M7-40A1		42.3		mF
C			Electrolyt		
LTE	expected lifetime calculated, forced air cooling	60			kHrs
	expected lifetime calculated, w/o forced air cooling	30			kHrs
Controller Interface Data					
V_S	supply voltage primary side	21.6	24	26.4	V
I_{SO}	supply current primary side (+ external current sensors)		270	1200	mA
V_{IT+}	Input threshold voltage (HIGH)			0,7*Vs	V
V_{IT-}	Input threshold voltage (LOW)	0.3*Vs			V
R_{IN}	Input resistance		10		k Ω
I_{TRIPSC}	Over current trip level		3600		A _{PEAK}
T_{tp}	Over temperature protection level		100		$^{\circ}\text{C}$
Mechanical Data					
dv/dt_{AIR}	required airflow per fan	620			m ³ /h
w	approx. total weight		110		kg
Size	Width x Depth x Height (with fan)	1122	752	544	mm
T_{stg}	w/o need of reforming the caps	-20		40	$^{\circ}\text{C}$
T_{amb}		-20		55	$^{\circ}\text{C}$
T_{hs}					$^{\circ}\text{C}$
Alltitude	installation height w/o derating			1000	m
Protection			IP00		
Pollution	EN 50178		2		
Fan Data					
Fan	included in the stack (NO)				
Type	(SKF 16 O-230-01)				
V_{Fan}	Fan voltage		230		V
f_{FAN}	Fan frequency		50		Hz
I_{FAN}	Fan current		1.3		A
P_{FAN}	Fan power		300		W



B6CI

PIN Array X1

PIN	Signal	Function	Specifications
X1:01	IF_PWR_VP	Power Supply	Supply voltage +24V _{DC} (±10%) IN
X1:02	IF_PWR_GND	IF_HB	
X1:03	IF_PWR_VP	Power Supply	Supply voltage +24V _{DC} (±10%) IN
X1:04	IF_PWR_GND	GND_for_IF_PWR_VP	
X1:05	IF_PWR_VP	Power Supply	Supply voltage +24V _{DC} (±10%) IN
X1:06	IF_PWR_GND	GND_for_IF_PWR_VP	
X1:07	IF_CMN_rsrvd	Reserved	
X1:08	IF_CMN_GND	GND for IF_CMN_nHALT, IF_CMNrsvd	
X1:09	IF_CMN_nHALT	Status signal	Digital IF_PWR_VP logic LOW (dominant) = not ready to operate HIGH (recessive) = ready to operate
X1:10	IF_CMN_GPIO	General purpose IO	Inverted IF_CMN_nHALT signal Signal propagation time to IF_CMN_nHALT signal: 100µs (typ.)
X1:11	IF_CMN_ANLG0	Temperature analog out	Max. output current: 5mA Turns ratio: 100mV/°C Max. voltage range: +15V Nominal voltage range: 0...10V
X1:12	IF_CMN_AGND0	GND for IF_CMN_ANLG0	
X1:13	IF_CMN_ANLG1	U _{DC} analog out	Max. output current: 5mA Turns ratio: 10mV/V Max. voltage range: +15V Nominal voltage range: 0...10V
X1:14	IF_CMN_AGND1	GND for IF_CMN_ANLG1	
X1:15	IF_HB1_TOP	Switching signal input (HB1 TOP switch)	Digital IF_PWR_VP logic LOW = TOP switch off HIGH = TOP switch on
X1:16	IF_HB1_TOP	Switching signal input (HB1 BOT switch)	Digital IF_PWR_VP logic LOW = BOT switch off HIGH = BOT switch on
X1:17	IF_HB1_rsrvd	Reserved	
X1:18	IF_HB1_GND	GND for IF_HB1_TOP, IF_HB1_BOT, IF_HB1_rsrvd	
X1:19	IF_HB1_ANLG	I analog out HB1	Max. output current: 5mA Turns ratio: 3mV/A Max. voltage range: ±15V Nominal voltage range: -10...10V
X1:20	IF_HB1_AGND	GND for IF_HB1_ANLG	



Product information of suitable female connectors and distributor contact information is available at e.g. <http://www.harting.com> (part number 09 18 520 7 813 – female connector with strain relief clamp).

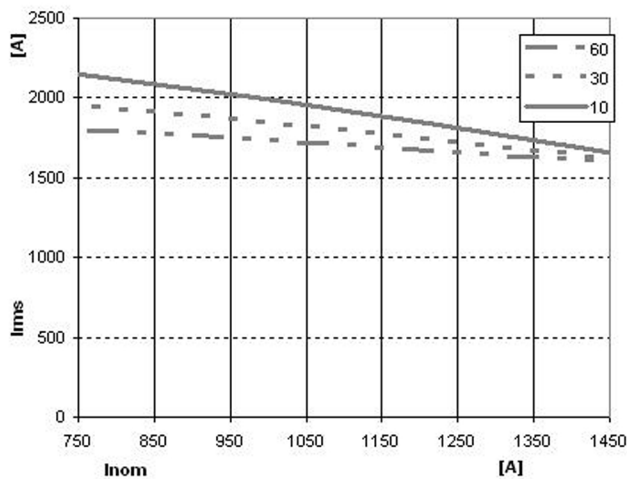


Fig. 1 Maximum overload current, $T_{amb} = 40^\circ C$

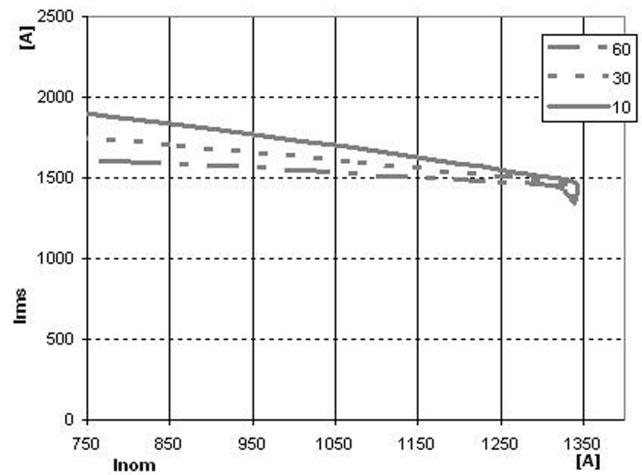


Fig. 2 Maximum overload current, $T_{amb} = 50^\circ C$

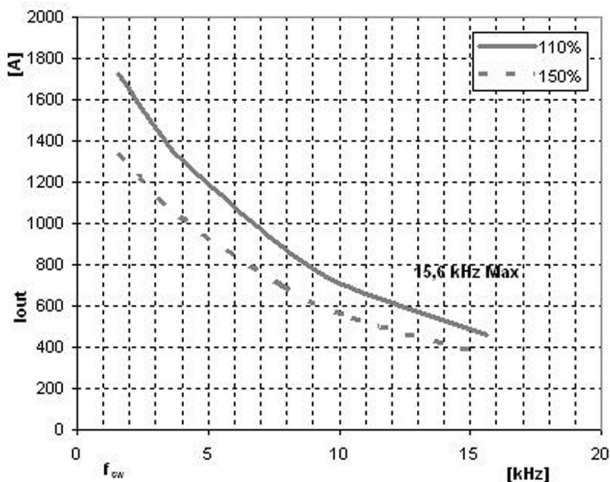


Fig. 3 Max permanent inverter curr. vs. f_{sw} , $T_{amb} = 40^\circ C$

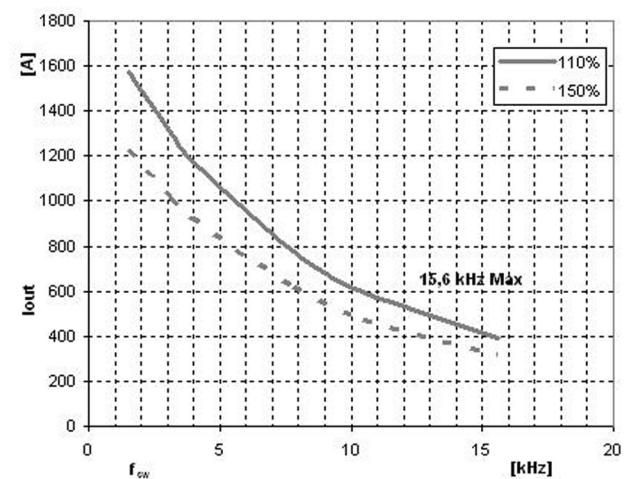


Fig. 4 Max. permanent inverter curr. vs. f_{sw} , $T_{amb} = 50^\circ C$

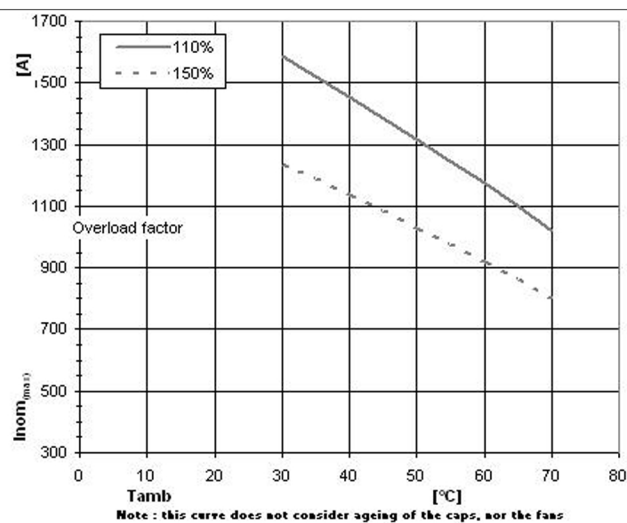


Fig. 5 Max. nominal curr. vs. ambient temperature

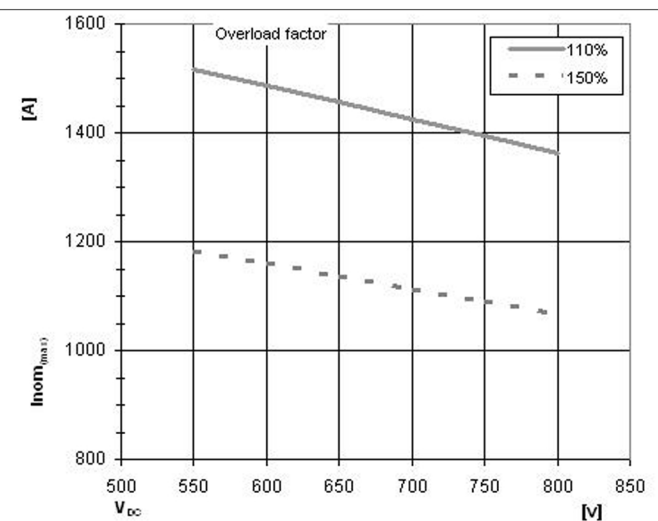
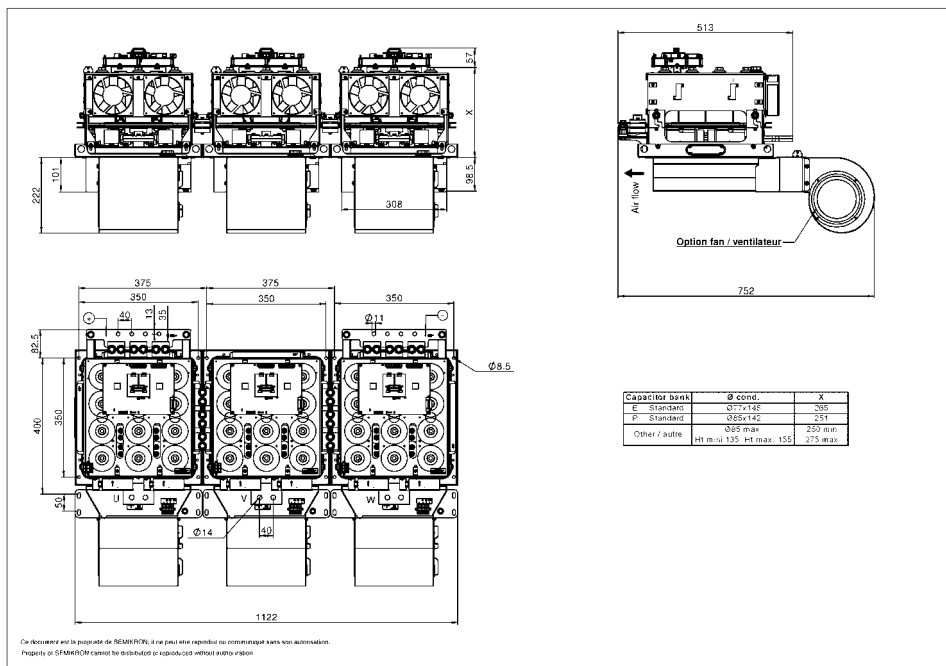
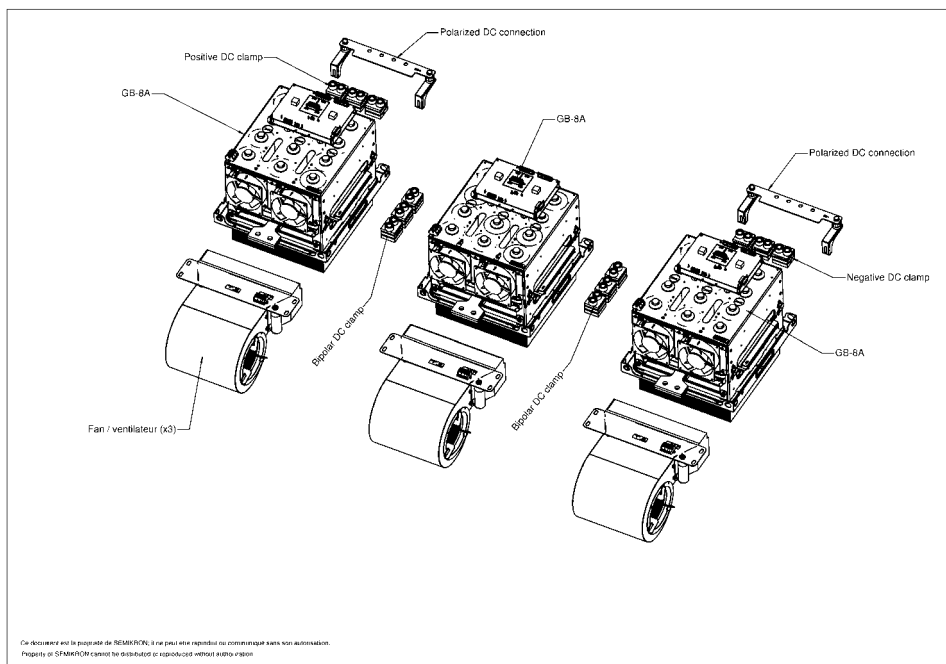


Fig. 6 Maximum nominal current vs. DC Link voltage

IGD-8-426-E1F12-BH-FA



SEMİKUBE GD-8HA, Px308/308



3D view of the SEMIKUBE Size '3'

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.